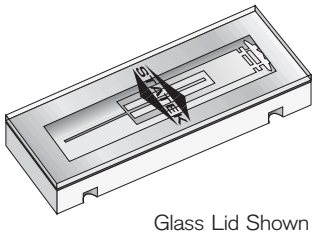
CX3SM CRYSTAL

800 kHz to 1.35 MHz

Low Profile Miniature Surface Mount Quartz Crystal

DESCRIPTION

The CX3SM quartz crystals are leadless devices designed for surface mounting on printed circuit boards or hybrid substrates. They are hermetically sealed in a rugged, miniature ceramic packages and are designed specifically for manufacturing temperatures up to 260°C.



Glass Lid Shown

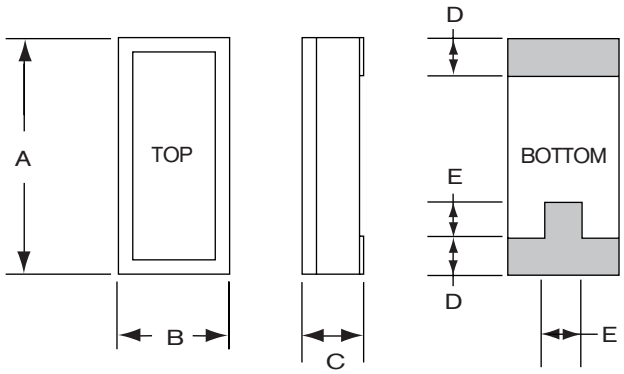
actual size

side view

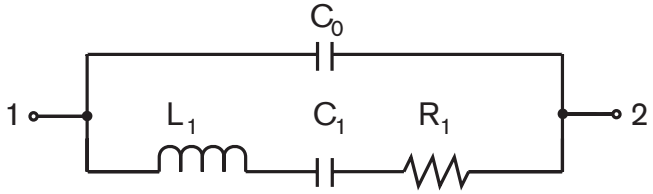
FEATURES

- Extensional mode
- Ideal for use with microprocessors
- Designed for low power applications
- Compatible with hybrid or PC board packaging
- Low aging
- Full military testing available
- Ideal for battery operated applications
- Designed and manufactured in the USA

PACKAGE DIMENSIONS



EQUIVALENT CIRCUIT

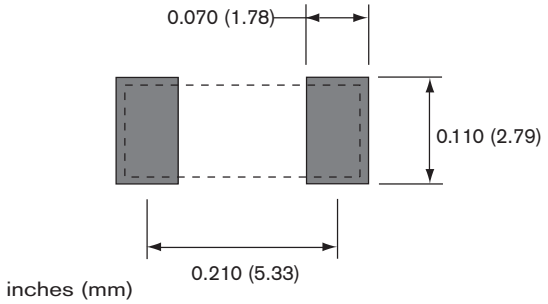


R_1 Motional Resistance L_1 Motional Inductance
C_1 Motional Capacitance C_0 Shunt Capacitance

	TYP.		MAX.	
DIM	inches	mm	inches	mm
A	0.263	6.68	0.270	6.86
B	0.097	2.46	0.104	2.64
C	-	-	see below	
D	0.052	1.32	0.058	1.47
E	0.030	0.76	0.035	0.89

DIM "C"	GLASS LID		CERAMIC LID	
MAX	inches	mm	inches	mm
SM1	0.053	1.35	0.067	1.70
SM2/SM4	0.055	1.40	0.069	1.75
SM3/SM5	0.058	1.47	0.072	1.83

SUGGESTED LAND PATTERN



inches (mm)

STATEK CORPORATION 512 N. MAIN ST., ORANGE, CA 92868 714-639-7810 FAX: 714-997-1256 **www.statek.com**

SPECIFICATIONS

Specifications are typical at 25°C unless otherwise noted.
Specifications are subject to change without notice.

Frequency Range	800 kHz - 1.35 MHz
Functional Mode	Extensional
Calibration Tolerance[1]	± 500 ppm (0.05%) ± 1000 ppm (0.1%) ± 10000 ppm (1.0%)
Load Capacitance	7 pF
Motional Resistance (R_1)	5 kΩ MAX
Motional Capacitance (C_1)	1.2 fF
Quality Factor (Q)	150 k
Shunt Capacitance (C_0)	1.0 pF
Drive Level	3 μW MAX.
Turning Point (T_0)[2]	35°C
Temperature Coefficient (k)	-0.035 ppm/°C[2]

Note: Frequency f at temperature T is related to frequency f_0 at turning point temperature T_0 by: $\frac{f-f_0}{f_0} = k(T-T_0)^2$

Aging, first year	5 ppm MAX
Shock, survival	1000 g, 0.3 ms,1/2 sine
Vibration, survival	10 g RMS, 20-1,000 Hz random
Operating Temp. Range	-10°C to +70°C (Commercial) -40°C to +85°C (Industrial) -55°C to +125°C (Military)
Storage Temp. Range	-55°C to +125°C
Max Process Temperature	260°C for 20 sec.

1. Tighter tolerances available.
2. Other values available.

PACKAGING OPTIONS

CX3SM - Tray Pack

- Tape and Reel
  (Reference tape and reel data sheet 10109)

TERMINATIONS

Designation	Termination
SM1	Gold Plated
SM2	Solder Plated
SM3	Solder Dipped
SM4	Solder Plated (Lead Free)
SM5	Solder Dipped (Lead Free)

HOW TO ORDER CX3SM CRYSTALS

CX3 S C SM1 – 1.0M , 500 / I

- S: "S" if special or custom design. Blank if Std.
- C: Blank = Glass Lid; C = Ceramic Lid
- SM1: SM1 = Gold Plated; SM2 = Solder Plated; SM3 = Solder Dipped; SM4 = Solder Plated (Lead Free); SM5 = Solder Dipped (Lead Free)
- 1.0M: Frequency K = kHz, M = MHz
- 500: Calibration Tolerance @ 25°C (in ppm)
- I: Operating Temp. Range: C = -10°C to +70°C; I = -40°C to +85°C; M = -55°C to +125°C; S = Customer Specified

TYPICAL APPLICATION FOR A PIERCE OSCILLATOR

The low profile CX miniature surface mount crystal is ideal for small, high density, battery operated portable products. The CX crystal designed in a Pierce oscillator (single inverter) circuit provides very low current consumption and high stability. A conventional CMOS Pierce oscillator circuit is shown below. The crystal is effectively inductive and in a PI-network circuit with C_D and C_G provides the additional phase shift necessary to sustain oscillation. The oscillation frequency (f_0) is 15 to 150 ppm above the crystal's series resonant frequency (f_S).

Drive Level

R_A is used to limit the crystal's drive level by forming a voltage divider between R_A and C_D. R_A also stabilizes the oscillator against changes in the amplifiers output resistance (R_0). R_A should be increased for higher voltage operation.

Load Capacitance

The CX crystal calibration tolerance is influenced by the effective circuit capacitances, specified as the load capacitance (C_L). C_L is approximately equal to:

$$C_L = \frac{C_D \times C_G}{C_D + C_G} + C_S \qquad (1)$$

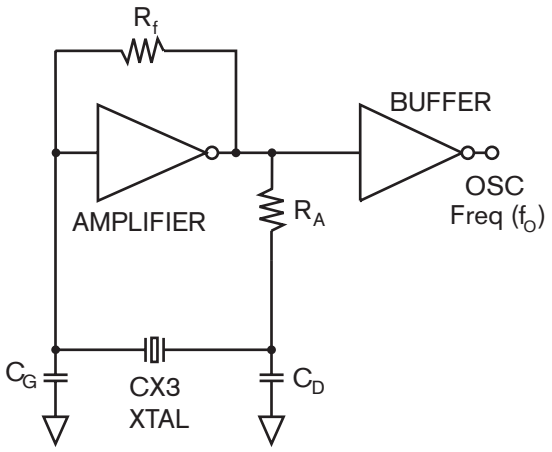
NOTE: C_D and C_G include stray layout to ground and C_S is the stray shunt capacitance between the crystal terminal. In practice, the effective value of C_L will be less than that calculated from C_D, C_G and C_S values because of the effect of the amplifier output resistance. C_S should be minimized.

The oscillation frequency (f_0) is approximately equal to:

$$f_0 = f_S \left[1 + \frac{C_1}{2(C_0 + C_L)} \right] \qquad (2)$$

Where f_S = Series resonant frequency of the crystal
C_1 = Motional Capacitance
C_0 = Shunt Capacitance

CONVENTIONAL CMOS PIERCE OSCILLATOR CIRCUIT



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